4-Bit Dual Supply Translating Transceiver with Configurable Voltage Translation; 3-State

General Description

The ET74LVCH4T245 is a 4-bit, dual supply transceiver that enables bidirectional level translation. It features two 4-bit input-output ports (nAn and nBn), a direction control input (DIR), an output enable input ($\overline{OE}$) and dual supply pins ($V_{CC(A)}$ and $V_{CC(B)}$). Both $V_{CC(A)}$ and $V_{CC(B)}$ can be supplied at any voltage between 0.8V and 3.6V making the device suitable for translating between any of the low voltage nodes (1.2V, 1.8V, 2.5V, 3.3V, 3.6V, 4.5V, 5V and 5.5V). Pins nAn, $\overline{OE}$ and DIR are referenced to $V_{CC(A)}$ and pins nBn are referenced to $V_{CC(B)}$. A HIGH on DIR allows transmission from nAn to nBn and a LOW on DIR allows transmission from nBn to nAn. The output enable input ($\overline{OE}$) can be used to disable the outputs so the buses are effectively isolated.

The device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either $V_{CC(A)}$ or $V_{CC(B)}$ are at GND level, both An and Bn outputs are in the high-impedance OFF-state. The bus-hold circuitry on the powered-up side always stays active.

The ET74LVCH4T245 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

Features

- Wide Supply Voltage Range:
  -- $V_{CC(A)}$: 1.2V to 5.5V
  -- $V_{CC(B)}$: 1.2V to 5.5V
- Fully Configurable Dual-Rail Design
- Maximum Data Rates:
  -- 420Mbit/s (3.3V to 5.0V Translation)
  -- 210Mbit/s (Translate to 3.3V)
  -- 140Mbit/s (Translate to 2.5V)
  -- 75Mbit/s (Translate to 1.8V)
  -- 60Mbit/s (Translate to 1.5V)
- Bus Hold on Data Inputs
- I_{OFF} Circuitry Provides Partial Power-down Mode Operation
- ESD Protection Complies with JESD22 Standard
  -- HBM: ±4000V Pass (JEDEC JS-001)
  -- CDM: ±1500V Pass (JEDEC JS-002)
- Latch Up Performance Exceeds ±100mA per JEDEC JESD78F

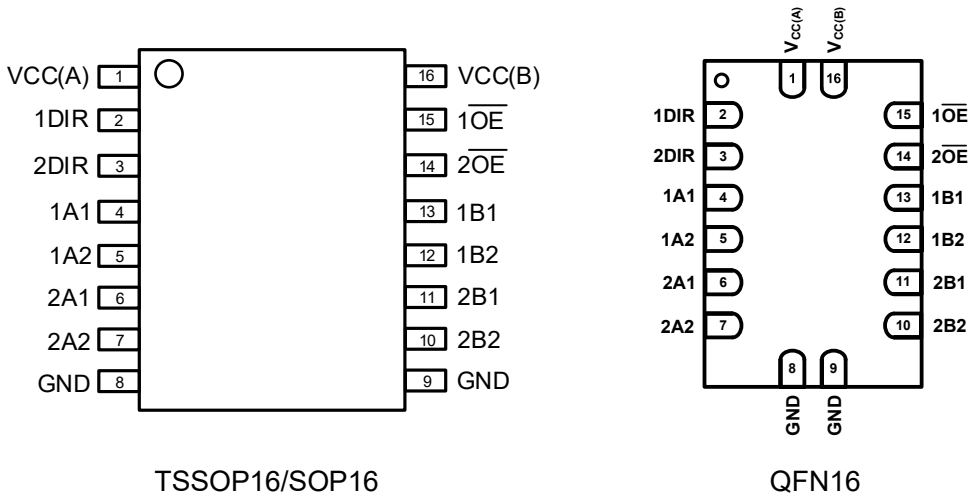
- Part No. and Package Information

Part No.	Package	MSL
ET74LVCH4T245V	TSSOP16 (4.4mm × 5mm)	3
ET74LVCH4T245Y	QFN16 (2.5mm × 3.5mm)	3
ET74AVCH4T245M	SOP16 (9.9mm × 3.9mm)	3

Applications

- Personal Electronic
- Industrial Equipment
- Enterprise Infrastructure
- Telecom Equipment

Pin Configuration



TSSOP16/SOP16 QFN16

Figure1. Pin Configuration

Pin Function

Pin		I/O	Description
Pin Name	TSSOP16/SOP16/QFN16		
VCC(A)	1	–	Supply Voltage Pin of A Side
VCC(B)	16	–	Supply Voltage Pin of B Side
1DIR,2DIR	2,3	I	Direction-control Signal. Referenced to VCC(A)
$2\overline{OE}$,$1\overline{OE}$	14,15	I	3-state Output-mode Enables. Pull $\overline{OE}$ high to place all outputs in 3-state mode. Referenced to VCC(A)
1A1~2A2	4~7	I/O	Input/Output 1A1~2A2.Referenced to VCC(A)
2B2~1B1	10~13	I/O	Input/Output 2B2~1B1.Referenced to VCC(B)
GND	8,9	–	Ground

Functional Diagram

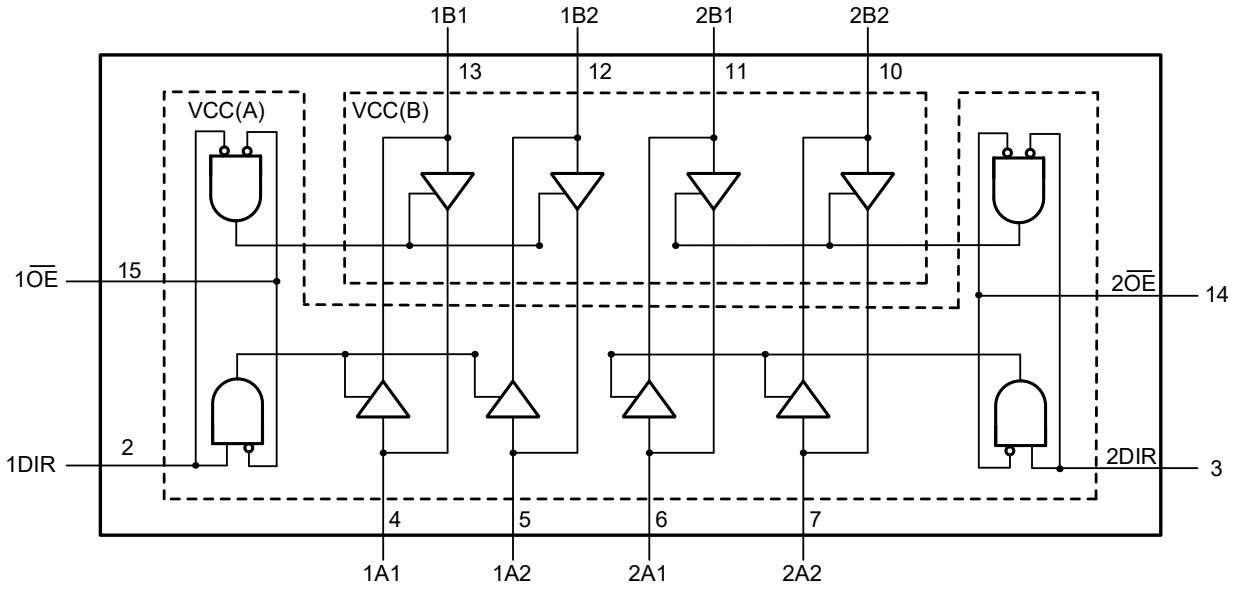


Figure2. Logic Symbol

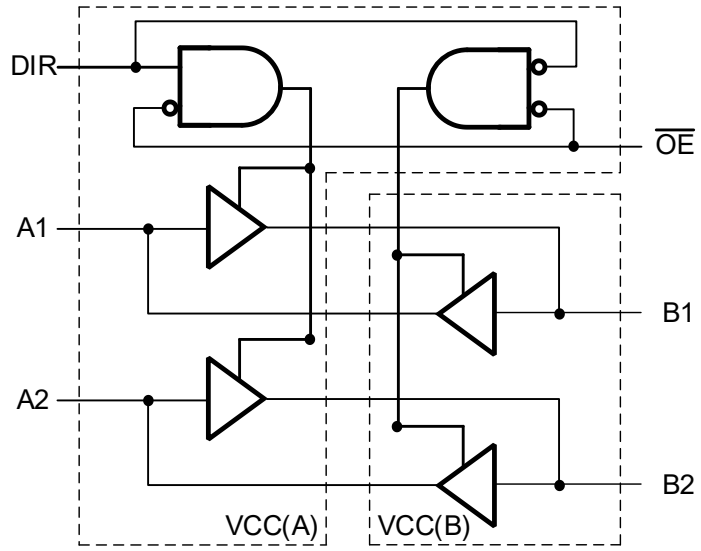


Figure3. Logic Diagram

Functional Description

Table 1. Function table[1]

Supply Voltage	Input		Input/Output	
$V_{CC(A)}$, $V_{CC(B)}$	$n\overline{OE}$[2]	nDIR[2]	nAn[2]	nBn[2]
1.2V to 5.5V	L	L	nAn = nBn	Input
1.2V to 5.5V	L	H	input	nBn = nAn
1.2V to 5.5V	H	X	Hi-Z	Hi-Z
GND[3]	X	X	Hi-Z	Hi-Z

Note1: H = High Voltage Level; L = Low Voltage Level; X = Don't Care; Z = High-impedance OFF-state.

Note2: The nAn, DIR and $\overline{OE}$ input circuit is referenced to $V_{CC(A)}$; The Bn input circuit is referenced to $V_{CC(B)}$.

Note3: If at least one of $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into suspend mode.

Absolute Maximum Ratings

Symbol	Parameter	Conditions	Rating	Unit
$V_{CC(A)}$	Supply Voltage A Side (VCC(A) Pin)		-0.5~6.5	V
$V_{CC(B)}$	Supply Voltage B Side (VCC(B) Pin)		-0.5~6.5	V
I_{IK}	Input Clamping Current	V_I < 0V	-50	mA
V_I	Input Voltage[4]		-0.5~6.5	V
I_{OK}	Output Clamping Current	V_O < 0V	-50	mA
V_O	Output Voltage	Active Mode[5]	-0.5~V_{CCO} + 0.5	V
		Suspend or 3-state Mode	-0.5~6.5	V
I_O	Output Current	V_O = 0V to V_{CC}	±50	mA
I_{CC}	Supply Current	Per VCC(A) or VCC(B) Pin	+100	mA
I_{GND}	Ground Current	Per GND Pin	-100	mA
T_{STG}	Storage Temperature		-65 to 150	°C
T_J	Operating Junction Range		-40 to 150	°C
V_{ESD}	Human Body Mode[6]		±4000	V
	Charged Device Mode[7]		±1500	V
I_{LU}	Latch-up Current[8]		±100	mA

Note4: I/O absolute maximum rating must be observed.

Note5: V_{CCO} is the supply voltage associated with the output port.

Note6: HBM tested per JEDEC JS-001.

Note7: CDM tested per JEDEC JS-002.

Note8: Latch Up Current Maximum Rating tested per JEDEC JESD78F.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Rating	Unit
$V_{CC(A)}$	Supply Voltage A Side (VCC(A) Pin)		1.2~5.5	V
$V_{CC(B)}$	Supply Voltage B Side (VCC(B) Pin)		1.2~5.5	V
V_I	Input Voltage		0~5.5	V
V_O	Output Voltage	Active Mode	0~V_{CCO}	V
		Suspend or 3-state	0~5.5	V
T_A	Operating Ambient Temperature		-40 to 125	°C
t_r, t_f	Input Rise and Fall Time	V_{CCI} = 1.2V to 5.5V (9)	5	ns/V

Note9: V_{CCI} is the supply voltage associated with the input port.

Electrical Characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0V).
V_{CCI} is the supply voltage associated with the data input port; V_{CCO} is the supply voltage associated with the output port.

Symbol	Parameter	Conditions	T_A = 25°C			Unit
			Min	Typ	Max	
V_{OH}	High-Level Output Voltage	V_I = V_{IH} or V_{IL}; I_O = -3mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V		1.09		V
V_{OL}	Low-Level Output Voltage	V_I = V_{IH} or V_{IL}; I_O = 3mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V		0.07		V
I_I	Input Leakage Current	DIR, $\overline{OE}$ Input; V_I = 0V or 5.5V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V to 5.5V			±1	μA
I_{BHL} (10)	Bus Hold LOW Current	A or B Port; V_I = 0.42V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V		26		μA
I_{BHH} (10)	Bus Hold HIGH Current	A or B Port; V_I = 0.78V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V		-24		μA
I_{BHLO} (10) (11)	Bus Hold LOW Overdrive Current	$V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V		27		μA
I_{BHHO} (10) (11)	Bus Hold HIGH Overdrive Current	$V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V		-26		μA
I_{OZ}	Off-State Output Current	A or B Port; V_O = 0V or V_{CCO}; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V to 5.5V			±2.5	μA
		Suspend Mode A Port; V_O = 0V or V_{CCO}; $V_{CC(A)}$ = 5.5V; $V_{CC(B)}$ = 0V			±2.5	μA
		Suspend Mode B Port; V_O = 0V or V_{CCO}; $V_{CC(A)}$ = 0V; $V_{CC(B)}$ = 5.5V			±2.5	μA
I_{OFF}	Power-Off Leakage Current	A Port; V_I or V_O = 0V to 5.5V; $V_{CC(A)}$ = 0V; $V_{CC(B)}$ = 1.2V to 5.5V			±1	μA
		B Port; V_I or V_O = 0V to 5.5V; $V_{CC(B)}$ = 0V; $V_{CC(A)}$ = 1.2V to 5.5V			±1	μA
C_I	Input Capacitance	DIR, $\overline{OE}$ Input; V_I = 0V or 3.3V; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.3V		2.2		pF
$C_{I/O}$	Input/Output Capacitance	A and B Port; V_O = 3.3V or 0V; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.3V		6		pF

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	-40°C ≤ T_A ≤ 85°C		-40°C ≤ T_A ≤ 125°C		Unit
			Min	Max	Min	Max	
V_{IH}	High-Level Input Voltage	Data Input					
		V_{CCI} = 1.2V	0.8V_{CCI}		0.8V_{CCI}		V
		V_{CCI} = 1.4V to 1.95V	0.65V_{CCI}		0.65V_{CCI}		V
		V_{CCI} = 2.3V to 2.70V	1.7		1.7		V
		V_{CCI} = 3.0V to 3.60V	2.0		2.0		V
		DIR, $\overline{OE}$ Input					
		$V_{CC(A)}$ = 1.2V	0.8$V_{CC(A)}$		0.8$V_{CC(A)}$		V
		V_{CCI} = 1.4V to 1.95V	0.65$V_{CC(A)}$		0.65$V_{CC(A)}$		V
		V_{CCI} = 2.3V to 2.7V	1.7		1.7		V
		V_{CCI} = 3.0V to 3.6V	2.0		2.0		
		V_{CCI} = 4.5V to 5.5V	0.7$V_{CC(A)}$		0.7$V_{CC(A)}$		V
V_{IL}	Low-Level Input Voltage	Data Input					
		V_{CCI} = 1.2V		0.2V_{CCI}		0.2V_{CCI}	V
		V_{CCI} = 1.4V to 1.95V		0.35V_{CCI}		0.35V_{CCI}	V
		V_{CCI} = 2.3V to 2.7V		0.7		0.7	V
		V_{CCI} = 3.0V to 3.6V		0.8		0.8	V
		DIR, $\overline{OE}$ Input					
		$V_{CC(A)}$ = 1.2V		0.2$V_{CC(A)}$		0.2$V_{CC(A)}$	V
		V_{CCI} = 1.4V to 1.95V		0.35$V_{CC(A)}$		0.35$V_{CC(A)}$	V
		V_{CCI} = 2.3V to 2.7V		0.7		0.7	V
		V_{CCI} = 3.0V to 3.6V		0.8		0.8	
		V_{CCI} = 4.5V to 5.5V		0.3$V_{CC(A)}$		0.3$V_{CC(A)}$	V
V_{OH}	High-Level Output Voltage	V_I = V_{IH} or V_{IL}					
		I_O = -100μA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V to 4.5V	V_{CCO} - 0.1		V_{CCO} - 0.1		V
		I_O = -6mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.4V	1.0		1.0		V
		I_O = -8mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.65V	1.2		1.2		V
		I_O = -12mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 2.3V	1.9		1.9		V
		I_O = -24mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.0V	2.4		2.4		V
		I_O = -32mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 4.5V	3.8		3.8		V
V_{OL}	Low-Level Output Voltage	V_I = V_{IH} or V_{IL}					
		I_O = 100μA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V to 4.5V		0.1		0.1	V
		I_O = 6mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.4V		0.3		0.3	V
		I_O = 8mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.65V		0.45		0.45	V
		I_O = 12mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 2.3V		0.3		0.3	V
		I_O = 24mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.0V		0.55		0.55	V
		I_O = 32mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 4.5V		0.55		0.55	V

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	-40°C ≤ T_A ≤ 85°C		-40°C ≤ T_A ≤ 125°C		Unit
			Min	Max	Min	Max	
I_I	Input Leakage Current	DIR, $\overline{OE}$ Input; V_I = 0V or 5.5V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V to 5.5V		±2		±10	μA
I_{BHL} (10)	Bus Hold LOW Current	A or B Port					
		V_I = 0.49V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.4V	15		10		μA
		V_I = 0.58V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.65V	25		20		μA
		V_I = 0.70V; $V_{CC(A)}$ = $V_{CC(B)}$ = 2.3V	45		45		μA
		V_I = 0.80V; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.0V	100		80		
		V_I = 1.35V; $V_{CC(A)}$ = $V_{CC(B)}$ = 4.5V	100		100		μA
I_{BHH} (10)	Bus Hold HIGH Current	A or B Port					
		V_I = 0.91V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.4V	-15		-10		μA
		V_I = 1.07V; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.65V	-25		-20		μA
		V_I = 1.60V; $V_{CC(A)}$ = $V_{CC(B)}$ = 2.3V	-45		-45		μA
		V_I = 2.00V; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.0V	-100		-80		
		V_I = 3.15V; $V_{CC(A)}$ = $V_{CC(B)}$ = 4.5V	-100		-100		μA
I_{BHLO} (10) (11)	Bus Hold LOW Overdrive Current	A or B Port					
		$V_{CC(A)}$ = $V_{CC(B)}$ = 1.6V	125		125		μA
		$V_{CC(A)}$ = $V_{CC(B)}$ = 1.95V	200		200		μA
		$V_{CC(A)}$ = $V_{CC(B)}$ = 2.7V	300		300		μA
		$V_{CC(A)}$ = $V_{CC(B)}$ = 3.6V	500		500		
		$V_{CC(A)}$ = $V_{CC(B)}$ = 5.5V	900		900		μA
I_{BHHO} (10) (11)	Bus Hold HIGH Overdrive Current	A or B Port					
		$V_{CC(A)}$ = $V_{CC(B)}$ = 1.6V	-125		-125		μA
		$V_{CC(A)}$ = $V_{CC(B)}$ = 1.95V	-200		-200		μA
		$V_{CC(A)}$ = $V_{CC(B)}$ = 2.7V	-300		-300		μA
		$V_{CC(A)}$ = $V_{CC(B)}$ = 3.6V	-500		-500		
		$V_{CC(A)}$ = $V_{CC(B)}$ = 5.5V	-900		-900		μA

Note10: '+/-' represents the direction of the current.

Note11: I_{BHL}, I_{BHH} means the bus hold current; I_{BHLO}, I_{BHHO} means the minimum overdrive current to flip the level.

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	-40°C ≤ T_A ≤ 85°C		-40°C ≤ T_A ≤ 125°C		Unit
			Min	Max	Min	Max	
I_{OZ}	Off-State Output Current	A or B Port; V_O = 0V or V_{CCO}; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.2V to 5.5V		±2		±10	μA
		Suspend Mode A Port; V_O = 0V or V_{CCO}; $V_{CC(A)}$ = 5.5V; $V_{CC(B)}$ = 0V		±2		±10	μA
		Suspend Mode B Port; V_O = 0V or V_{CCO}; $V_{CC(A)}$ = 0V; $V_{CC(B)}$ = 5.5V		±2		±10	μA
I_{OFF}	Power-Off Leakage Current	A Port; V_I or V_O = 0V to 5.5V; $V_{CC(A)}$ = 0V; $V_{CC(B)}$ = 1.2V to 5.5V		±5		±35	μA
		B Port; V_I or V_O = 0V to 5.5V; $V_{CC(B)}$ = 0V; $V_{CC(A)}$ = 1.2V to 5.5V		±5		±35	μA
I_{CC}	Supply Current	A Port; V_I = 0V or V_{CCI}; I_O = 0mA					
		$V_{CC(A)}$ = 1.2V to 5.5V; $V_{CC(B)}$ = 1.2V to 3.6V		10		12	μA
		$V_{CC(A)}$ = 5.5V; $V_{CC(B)}$ = 0V		16		12	μA
		$V_{CC(A)}$ = 0V; $V_{CC(B)}$ = 5.5V	-2		-8		μA
		B Port; V_I = 0V or V_{CCI}; I_O = 0mA					
		$V_{CC(A)}$ = 1.2V to 5.5V; $V_{CC(B)}$ = 1.2V to 5.5V		10		12	μA
		$V_{CC(A)}$ = 5.5V; $V_{CC(B)}$ = 0V		10		12	μA
		$V_{CC(A)}$ = 0V; $V_{CC(B)}$ = 5.5V	-2		-8		μA
		A Plus B Port ($I_{CC(A)}$ + $I_{CC(B)}$); I_O = 0mA; V_I = 0V or V_{CCI}; $V_{CC(A)}$ = 1.2V to 5.5V; $V_{CC(B)}$ = 1.2V to 5.5V		16			μA

Dynamic Characteristics

Typical switching characteristics at $V_{CC(A)}$ = 1.2V and T_A = 25°C (unless otherwise noted). Voltages are referenced to GND (ground = 0V); for test circuit see Figure6; for wave forms see Figure4 and Figure5.

t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.

Symbol	Parameter	Conditions	$V_{CC(B)}$				Unit
			1.2V	1.8V	3.3V	5.0V	
t_{pd}	Propagation Delay	nAn to nBn	11.0	7.4	5.7	5.4	ns
		nBn to nAn	11.0	9.5	8.9	8.9	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	9.5	9.5	9.5	9.5	ns
		$\overline{OE}$ to nBn	10.2	7.8	7.3	6.4	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	13.5	13.5	13.5	13.5	ns
		$\overline{OE}$ to nBn	13.6	8.9	7.1	7.0	ns

Dynamic Characteristics (Continued)

Typical switching characteristics at $V_{CC(B)}$ = 1.2V and T_A = 25°C (unless otherwise noted).Voltages are referenced to GND (ground = 0V); for test circuit see Figure6; for wave forms see Figure4 and Figure5. t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.

Symbol	Parameter	Conditions	$V_{CC(A)}$				Unit
			1.2V	1.8V	3.3V	5.0V	
t_{pd}	Propagation Delay	nAn to nBn	11.0	9.5	8.9	8.8	ns
		nBn to nAn	11.0	7.3	5.7	5.4	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	9.5	5.4	4.1	3.1	ns
		$\overline{OE}$ to nBn	10.2	8.6	7.8	7.8	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	13.5	6.9	3.8	3.2	ns
		$\overline{OE}$ to nBn	13.6	12.0	11.4	11.4	ns

Voltages are referenced to GND (ground = 0V), T_A = 25°C.

Symbol	Parameter	Conditions	$V_{CC(A)} = V_{CC(B)}$				Unit
			1.8V	2.5V	3.3V	5.0V	
C_{PD} (12) (13)	Power Dissipation Capacitance	A Port:(Direction A to B); B Port:(Direction B to A)	1	1	1	2	pF
		A Port:(Direction B to A); B Port:(Direction A to B)	13	13	13	13	pF

Note12: C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}{}^2 \times f_o)$ where:

f_i = Input Frequency in MHz;

f_o = Output Frequency in MHz;

C_L = Output Load capacitance in pF;

V_{CC} = Supply Voltage in V;

N = Number of Inputs Switching;

$\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = Sum of Outputs.

Note13: f_i = 10 MHz; V_I = GND to V_{CC}; $t_r = t_f$ = 1 ns; C_L = 0 pF; R_L = ∞ Ω.

Dynamic Characteristics (Continued)

Voltages are referenced to GND (ground = 0V), T_A = -40°C~85°C.

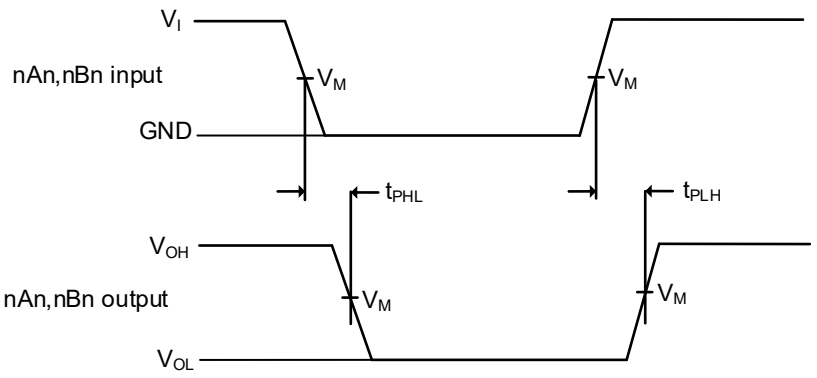
Symbol	Parameter	Conditions	$V_{CC(B)}$						Unit
			1.8V ± 0.15V		3.3V ± 0.3V		5V ± 0.5V		
			Min	Max	Min	Max	Min	Max	
$V_{CC(A)}$ = 1.65V to 1.95V									
t_{pd}	Propagation Delay	nAn to nBn	0.5	17.7	0.5	7.2	1.4	7.0	ns
		nBn to nAn	0.5	17.7	0.5	15.5	1.8	15.1	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	1.5	11.8	1.5	12.2	1.4	13.2	ns
		$\overline{OE}$ to nBn	2.4	18.5	1.7	17.1	1.3	9.6	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	0.4	10.8	0.4	10.8	0.4	11.7	ns
		$\overline{OE}$ to nBn	1.8	11.4	1.2	9.2	0.9	8.8	ns
$V_{CC(A)}$ = 3V to 3.6V									
t_{pd}	Propagation Delay	nAn to nBn	0.5	15.5	0.5	6.6	0.7	6.0	ns
		nBn to nAn	0.5	7.2	0.5	6.7	0.6	6.1	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	1.6	9.2	1.6	9.2	1.6	13.2	ns
		$\overline{OE}$ to nBn	2.1	18.8	1.5	14.2	0.8	8.9	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	0.8	6.8	0.8	7.3	0.8	8.3	ns
		$\overline{OE}$ to nBn	1.8	10.2	1.1	7.6	0.9	7.5	ns
$V_{CC(A)}$ = 4.5V to 5.5V									
t_{pd}	Propagation Delay	nAn to nBn	1.8	15.1	0.7	5.1	0.5	4.8	ns
		nBn to nAn	1.4	7.0	0.7	5.0	0.5	4.8	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	0.3	6.5	0.3	6.5	0.3	6.5	ns
		$\overline{OE}$ to nBn	2.0	16.8	1.4	10.7	0.7	9.6	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	0.7	6.8	0.7	6.8	0.7	6.8	ns
		$\overline{OE}$ to nBn	1.5	10.7	1.0	7.8	0.9	7.1	ns

Dynamic Characteristics (Continued)

Voltages are referenced to GND (ground = 0V), T_A = -40°C~125°C.

Symbol	Parameter	Conditions	$V_{CC(B)}$						Unit
			1.8V ± 0.15V		3.3V ± 0.3V		5V ± 0.5V		
			Min	Max	Min	Max	Min	Max	
$V_{CC(A)}$ = 1.65V to 1.95V									
t_{pd}	Propagation Delay	nAn to nBn	0.5	17.7	0.5	7.2	1.4	7.0	ns
		nBn to nAn	0.5	17.7	0.5	15.5	1.8	15.1	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	1.5	11.8	1.5	12.2	1.4	13.2	ns
		$\overline{OE}$ to nBn	2.4	18.5	1.7	17.1	1.3	9.6	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	0.4	10.8	0.4	10.8	0.4	11.7	ns
		$\overline{OE}$ to nBn	1.8	11.4	1.2	9.2	0.9	8.8	ns
$V_{CC(A)}$ = 3V to 3.6V									
t_{pd}	Propagation Delay	nAn to nBn	0.5	15.5	0.5	6.6	0.7	6.0	ns
		nBn to nAn	0.5	7.2	0.5	6.7	0.6	6.1	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	1.6	9.2	1.6	9.2	1.6	13.2	ns
		$\overline{OE}$ to nBn	2.1	18.8	1.5	14.2	0.8	8.9	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	0.8	6.8	0.8	7.3	0.8	8.3	ns
		$\overline{OE}$ to nBn	1.8	10.2	1.1	7.6	0.9	7.5	ns
$V_{CC(A)}$ = 4.5V to 5.5V									
t_{pd}	Propagation Delay	nAn to nBn	1.8	15.1	0.7	5.1	0.5	4.8	ns
		nBn to nAn	1.4	7.0	0.7	5.0	0.5	4.8	ns
t_{dis}	Disable Time	$\overline{OE}$ to nAn	0.3	6.5	0.3	6.5	0.3	6.5	ns
		$\overline{OE}$ to nBn	2.0	16.8	1.4	10.7	0.7	9.6	ns
t_{en}	Enable Time	$\overline{OE}$ to nAn	0.7	6.8	0.7	6.8	0.7	6.8	ns
		$\overline{OE}$ to nBn	1.5	10.7	1.0	7.8	0.9	7.1	ns

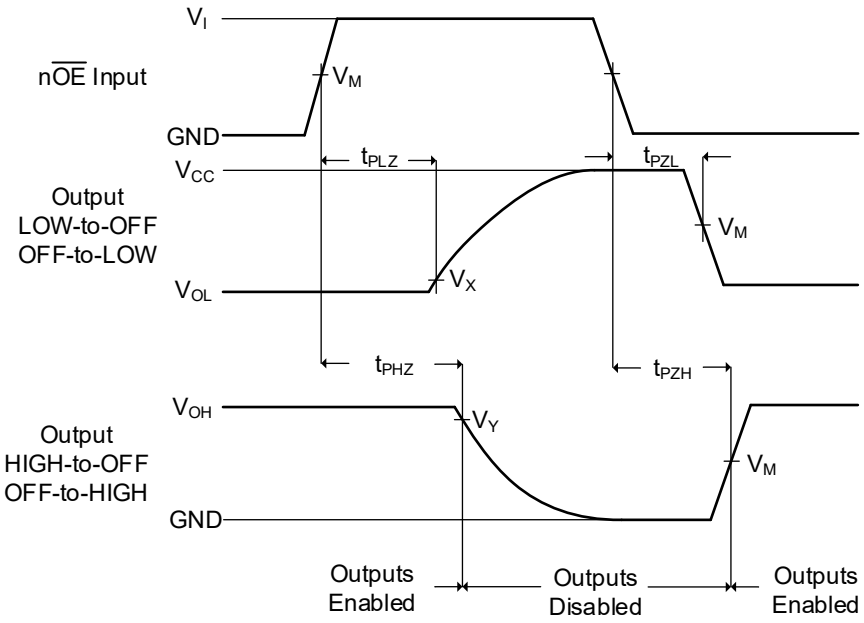
Test Circuit



Measurement points are given in Table 2.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure4. The data input (nAn, nBn) to output (nBn, nAn) propagation delay times



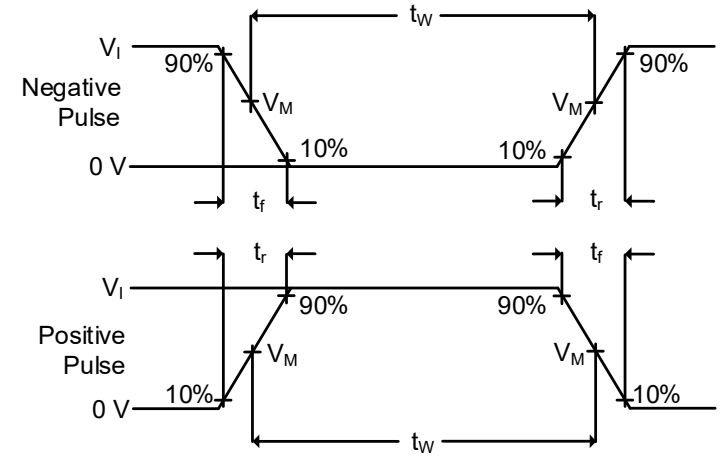
Measurement points are given in Table 2.

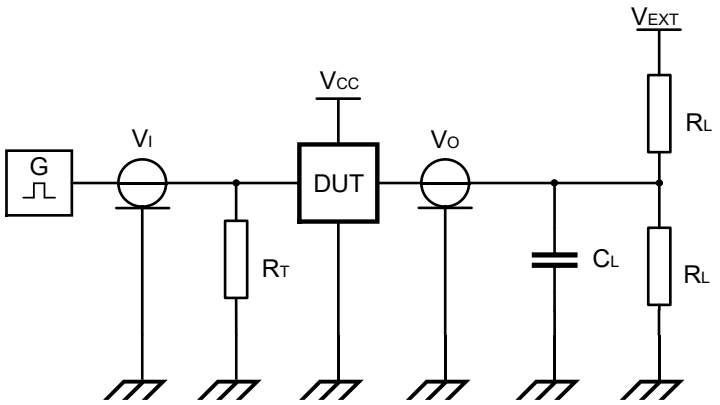
V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure5. Enable and disable times

Table 2. Measurement Points

Supply Voltage	Input	Output		
$V_{CC(A)}$, $V_{CC(B)}$	V_M	V_M	V_X	V_Y
1.2V to 1.6V	0.5 × V_{CCI}	0.5 × V_{CCO}	V_{OL} + 0.1V	V_{OH} - 0.1V
1.65V to 2.7V	0.5 × V_{CCI}	0.5 × V_{CCO}	V_{OL} + 0.15V	V_{OH} - 0.15V
3.0V to 5.5V	0.5 × V_{CCI}	0.5 × V_{CCO}	V_{OL} + 0.3V	V_{OH} - 0.3V





Measurement points are given in Table 3.

Definitions test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to output impedance Z_O of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Figure6. Test circuit for measuring switching times

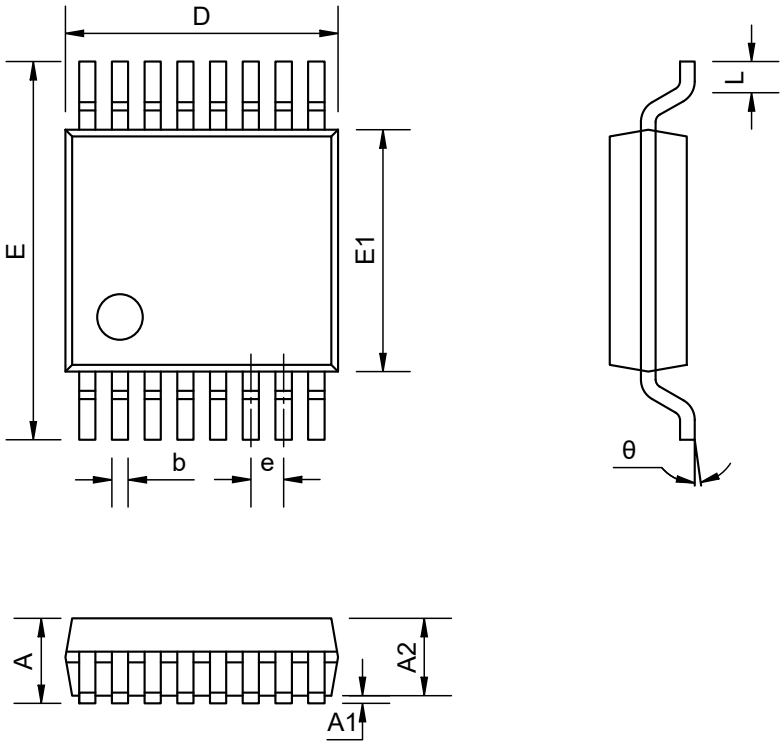
Table3. Test Data

Supply Voltage	Input		Load		V_{EXT}		
$V_{CC(A)}$, $V_{CC(B)}$	V_I	$\Delta t/\Delta V$[14]	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
1.2V to 5.5V	V_{CCI}	≤ 1.0ns/V	15pF	2kΩ	Open	GND	2 × V_{CCO}

Note14: dV/dt ≥ 1.0V/ns

Package Dimension

TSSOP16 (4.4mm × 5mm)

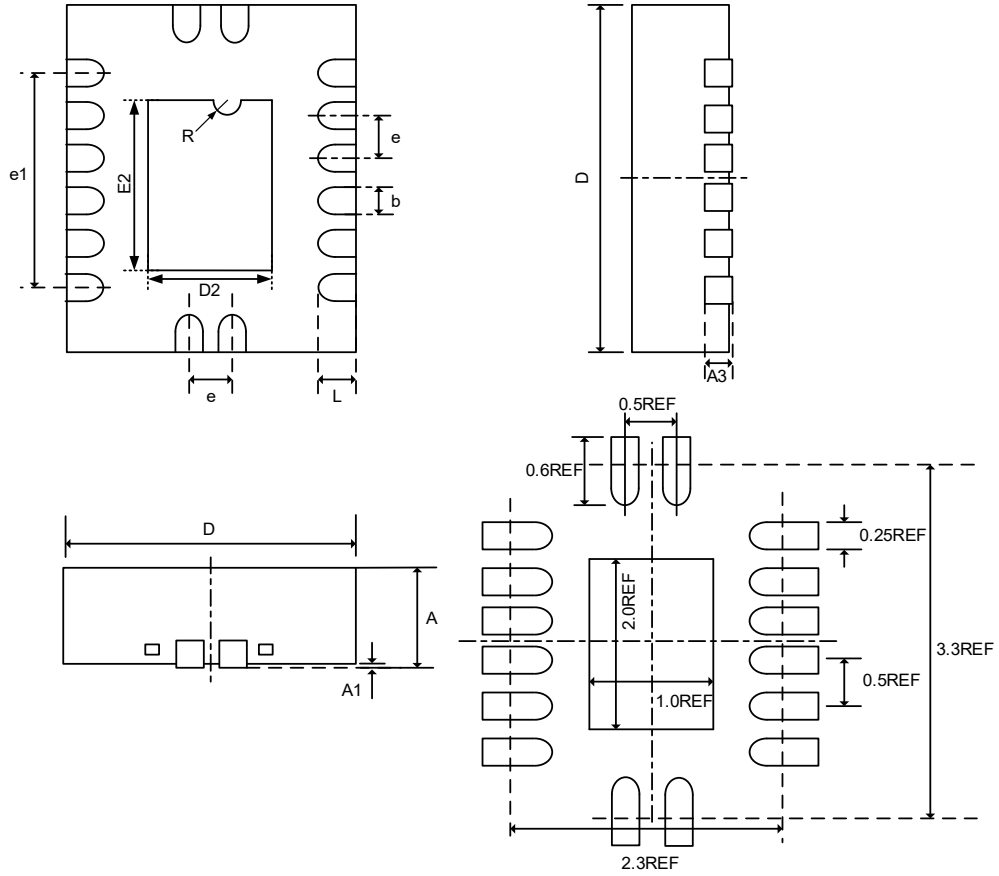


COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	--	--	1.10
A1	0.05	--	0.15
A2	0.80	--	1.00
b	0.19	--	0.30
D	4.90	5.00	5.10
E	6.25	6.40	6.55
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.50	0.60	0.70
θ	1°	--	7°

QFN16 (2.5mm × 3.5mm)

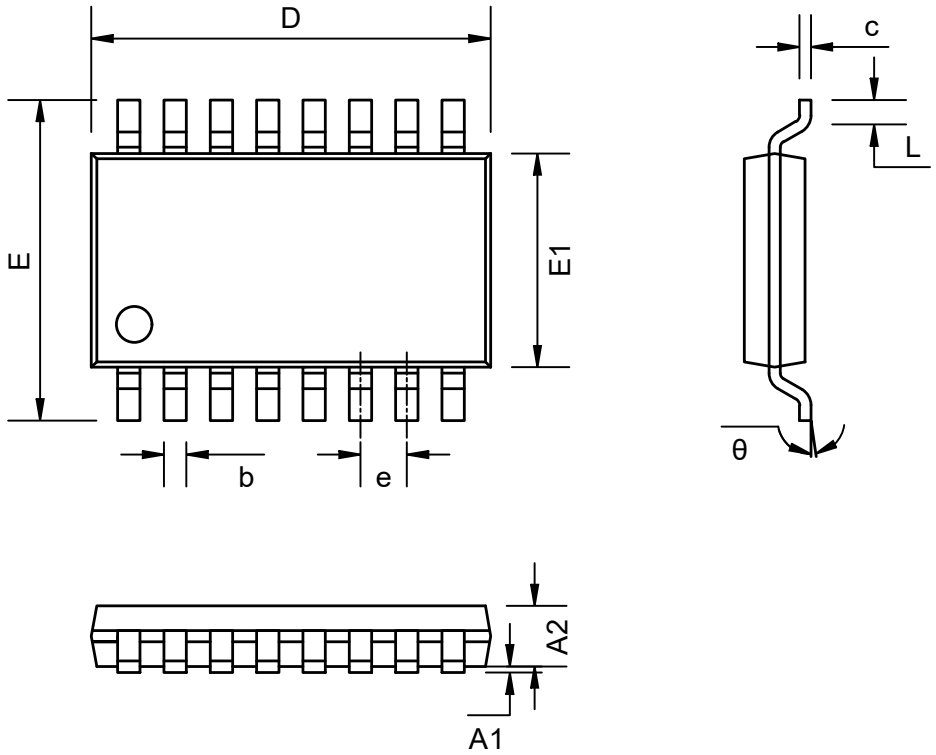


COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3		0.203REF	
b	0.20	0.25	0.30
D	2.45	2.50	2.55
E	3.45	3.50	3.55
D2	0.85	1.00	1.15
E2	1.85	2.00	2.15
e	0.45	0.50	0.55
E1	2.40	2.50	2.60
L	0.30	0.40	0.50
R		0.15REF	

SOP16 (9.9mm × 3.9mm)



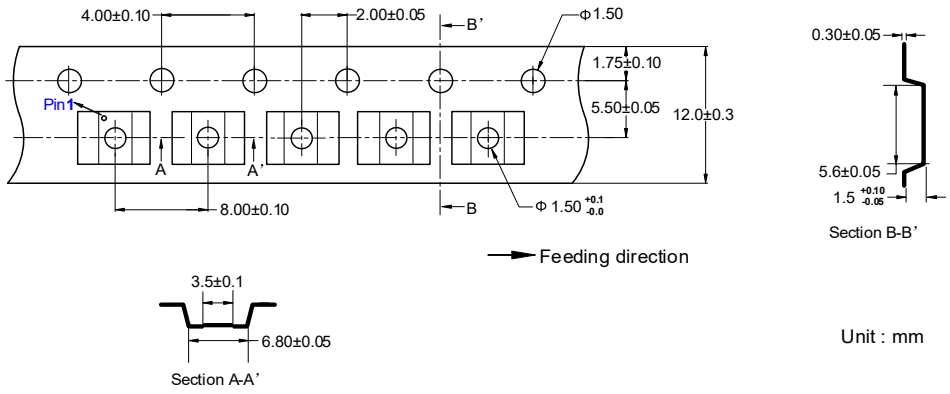
COMMON DIMENSIONS

(Unit: mm)

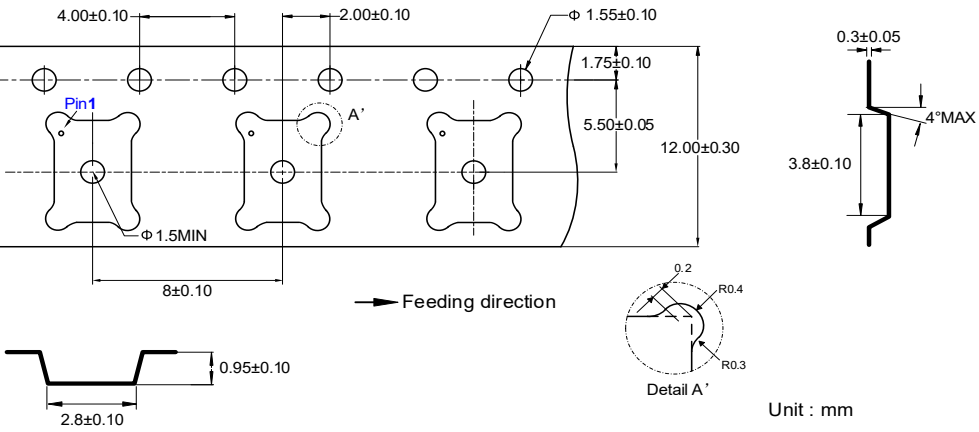
SYMBOL	MIN	NOM	MAX
A1	0.1	0.15	0.25
A2	1.35	1.45	1.55
b	0.36	--	0.51
c	0.18	--	0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.22	1.27	1.32
L	0.45	0.60	0.80
θ	0°	--	8°

Tape Information

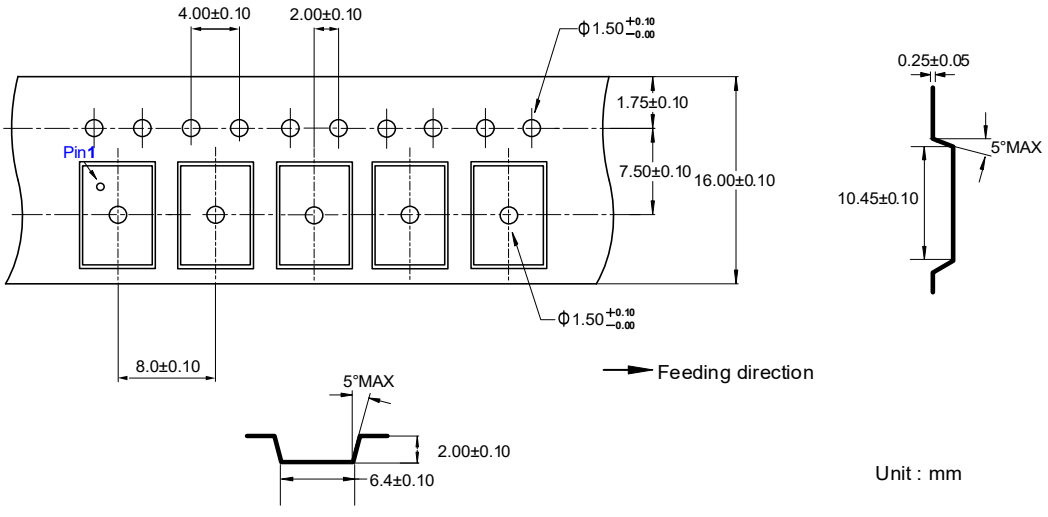
TSSOP16 (4.4mm × 5mm)



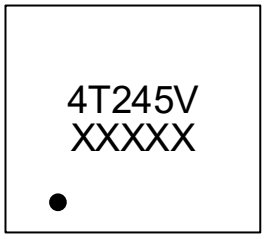
QFN16 (2.5mm × 3.5mm)



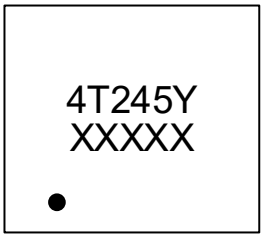
SOP16 (9.9mm × 3.9mm)



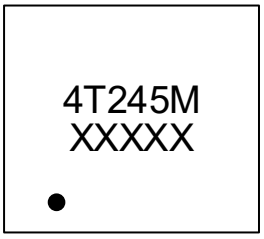
Marking Information



ET74LVCH4T245V
4T245V = Part Number
XXXXX = Tracking Number



ET74LVCH4T245Y
4T245Y = Part Number
XXXXX = Tracking Number



ET74LVCH4T245M
4T245M = Part Number
XXXXX = Tracking Number

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2025-11-29	Official Version	Wanganran	Yangxiaoxu	Liujy
1.1	2025-12-31	Update Format, Tape and Marking	Xu tao	Yang xiaoxu	Liu jiaying